TOSHIBA CMOS Digital Integrated Circuit Silicon Monolithic

TC7WG17FC

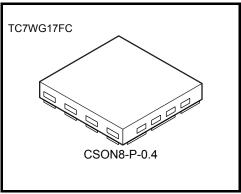
Triple Schmitt Buffer

Features

- High-level output current: $I_{OH}/I_{OL} = \pm 8 \text{ mA (min)}$ at V_{CC} = 3 V
- High-speed operation: t_{pd} = 4.0 ns (typ.)

at V_{CC} = 3.3 V,15pF

- Operating voltage range: V_{CC} = 0.9~3.6 V
- 5.5-V tolerant inputs
- 3.6-V power down protection outputs



Weight: 0.002 g (typ.)

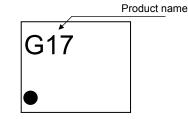
$ \begin{array}{c c c c c c c c c c c c c c c c c c c $	Characteristics	Symbol	Value	Unit
$ \begin{array}{c c} & & & & & & \\ \hline DC \mbox{ output voltage } & & & & \\ \hline V_{OUT} & & & & & \\ \hline -0.5 \sim V_{CC} + 0.5 & (Note 1) \\ \hline -0.5 \sim V_{CC} + 0.5 & (Note 2) \\ \hline \mbox{ Input diode current } & I_{IK} & -20 & m_{II} \\ \hline \mbox{ Output diode current } & I_{OK} & -20 & (Note 3) & m_{II} \\ \hline \mbox{ DC output current } & I_{OUT} & \pm 25 & m_{II} \\ \hline \mbox{ output current } & I_{OUT} & \pm 25 & m_{II} \\ \hline \mbox{ output current } & I_{OUT} & \pm 25 & m_{II} \\ \hline \mbox{ output current } & I_{OUT} & \pm 25 & m_{II} \\ \hline \mbox{ output current } & I_{OUT} & \pm 25 & m_{II} \\ \hline \mbox{ output current } & I_{OUT} & \pm 25 & m_{II} \\ \hline \mbox{ output current } & I_{OUT} & \pm 25 & m_{II} \\ \hline \mbox{ output current } & I_{OUT} & I_{OUT} & I_{OUT} \\ \hline \mbox{ output current } & I_{OUT} & I_{OUT} & I_{OUT} \\ \hline \mbox{ output current } & I_{OUT} & I_{OUT} & I_{OUT} \\ \hline \mbox{ output current } & I_{OUT} & I_{OUT} & I_{OUT} \\ \hline \mbox{ output current } & I_{OUT} & I_{OUT} & I_{OUT} \\ \hline \mbox{ output current } & I_{OUT} & I_{OUT} & I_{OUT} \\ \hline \mbox{ output current } & I_{OUT} & I_{OUT} & I_{OUT} \\ \hline \mbox{ output current } & I_{OUT} & I_{OUT} & I_{OUT} & I_{OUT} \\ \hline \mbox{ output current } & I_{OUT} & I_{OUT} & I_{OUT} & I_{OUT} \\ \hline \mbox{ output current } & I_{OUT} & I_{OUT} & I_{OUT} & I_{OUT} & I_{OUT} & I_{OUT} \\ \hline \mbox{ output current } & I_{OUT} & I_{OUT$	Power supply voltage	V _{CC}	-0.5~4.6	V
DC output voltage V_{OUT} $-0.5 \sim V_{CC} + 0.5$ (Note 2)Input diode current I_{IK} -20 m/Output diode current I_{OK} -20 (Note 3)m/DC output current I_{OUT} ± 25 m/	DC input voltage	V _{IN}	-0.5~7.0	V
$\begin{array}{ c c c c c c }\hline & 1001 & -0.5 \\ \hline & -0.5 \\ \hline & V_{CC} + 0.5 & (Note 2) \\\hline \\ \hline & Input diode current & I_{IK} & -20 & m_{I} \\\hline & 0utput diode current & I_{OK} & -20 & (Note 3) & m_{I} \\\hline & DC output current & I_{OUT} & \pm 25 & m_{I} \\\hline & 1001 &$			-0.5~4.6 (Note 1)	V
Output diode current I _{OK} -20 (Note 3) m/ DC output current I _{OUT} ±25 m/	DC output voltage	VOUI	-0.5~V _{CC} + 0.5 (Note 2)	v
DC output current I _{OUT} ±25 m/	Input diode current	I _{IK}	-20	mA
	Output diode current	I _{OK}	-20 (Note 3)	mA
	DC output current	IOUT	±25	mA
DC V _{CC} /GND current I _{CC} ±50 m/	DC V _{CC} /GND current	ICC	±50	mA
Power dissipation P _D 150 (Note 4) mV	Power dissipation	PD	150 (Note 4)	mW
Storage temperature T _{stg} -65~150 °C	Storage temperature	T _{stg}	-65~150	°C

Absolute Maximum Ratings (Ta = 25°C)

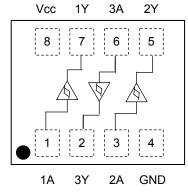
- Note: Using continuously under heavy loads (e.g. the application of high temperature/current/voltage and the significant change in temperature, etc.) may cause this product to decrease in the reliability significantly even if the operating conditions (i.e. operating temperature/current/voltage, etc.) are within the absolute maximum ratings and the operating ranges. Please design the appropriate reliability upon reviewing the Toshiba Semiconductor Reliability Handbook ("Handling Precautions"/Derating Concept and Methods) and individual reliability data (i.e. reliability test report and estimated failure rate, etc).
- Note 1: $V_{CC} = 0V$
- Note 2: High or Low State.
- I_{OUT} absolute maximum rating must be observed. Note 3: V_{OUT} < GND
- Note 4: Mounted on an FR4 board.

 $(25.4 \text{ mm} \times 25.4 \text{ mm} \times 1.6 \text{ t}, \text{ Cu Pad: } 11.56 \text{ mm}^2)$

Marking



Pin Assignment (top view)

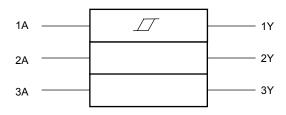


<u>TOSHIBA</u>

Truth Table

А	Y
L	L
Н	Н

IEC Logic Symbol



Operating Ranges

Characteristics	Symbol	Value	Unit
Power supply voltage	V _{CC}	0.9~3.6	V
Input voltage	V _{IN}	0~5.5	V
	Vau	0~3.6 (Note 5)	V
Output voltage	Vout	0~V _{CC} (Note 6)	v
		±8.0 (Note 7)	
Output Current		±4.0 (Note 8)	
	I _{OH} /I _{OL}	±3.0 (Note 9)	~^^
		±1.7 (Note 10)	mA
		±0.3 (Note 11)	
		±0.02 (Note 12)	
Operating temperature	T _{opr}	-40~85	°C

Note 5: $V_{CC} = 0 V$

Note 6: High or Low state.

Note 7: $V_{CC} = 3.0 \sim 3.6 \text{ V}$

Note 8: V_{CC} = 2.3~2.7 V

Note 9: V_{CC} = 1.65~1.95 V

Note 10: V_{CC} = 1.4~1.6 V

Note 11: $V_{CC} = 1.1 \sim 1.3 \text{ V}$

Note 12: $V_{CC} = 0.9 V$

Electrical Characteristics

DC Electrical Characteristics

Characteristics		Symbol	Test Condition		Ta = 25°C)	Ta = -40~85°C		Unit	
		Symbol	1630	Test Condition		Min	Тур.	Max	Min	Max	Unit
					0.9	—	_	0.73	_	0.80	
				1.1	_	_	0.86	_	0.93	- - - V	
	¥-			1.4	_	_	1.07	_	1.12		
	High level	VP	_		1.65	_	_	1.23	_		1.25
					2.3	_	_	1.66	_		1.68
Threshold voltage					3.0	_	_	2.14	_		2.15
Threshold voltage					0.9	0.18	_	—	0.07		_
				1.1	0.26			0.18	_		
	L avri lavral	V			1.4	0.36			0.31	_	
	Low level	V _N		_	1.65	0.45			0.41	_	
					2.3	0.69		—	0.64	_	•
					3.0	0.96			0.91	_	
					0.9	0.20		0.38	0.15	0.53	
					1.1	0.25		0.41	0.21	0.53	
Hysteresis voltage		Max			1.4	0.35		0.48	0.34	0.57	
	V _H			1.65	0.42		0.56	0.40	0.60	V	
				2.3	0.60		0.74	0.61	0.76		
					3.0	0.79		0.93	0.80	0.94	
		ih level V _{OH}		I _{OH} =-0.02 mA	0.9	0.75			0.75	_	V
				I _{OH} = -0.3 mA	1.1~1.3	V _{CC} × 0.75	_	_	V _{CC} × 0.75	_	
	High level			I _{OH} = -1.7 mA	1.4~1.6	V _{CC} × 0.75		_	$\begin{array}{c} V_{CC} \\ \times \ 0.75 \end{array}$		
	0			I _{OH} = -3.0 mA	1.65~ 1.95	V _{CC} -0.45		_	V _{CC} -0.45		
				I _{OH} = -4.0 mA	2.3~2.7	2.0			2.0	_	
				I _{OH} = -8.0 mA	3.0~3.6	2.48	_		2.48		
Output voltage		r level V _{OL}	V _{OL} V _{IN} = V _{IL}	I _{OL} = 0.02 mA	0.9			0.1		0.1	
				I _{OL} = 0.3 mA	1.1~1.3	_		V _{CC} × 0.25		$\begin{array}{c} V_{CC} \\ \times \ 0.25 \end{array}$	
Low le	Low level			I _{OL} = 1.7 mA	1.4~1.6	_		V _{CC} × 0.25		$\begin{array}{c} V_{CC} \\ \times \ 0.25 \end{array}$	
				I _{OL} = 3.0 mA	1.65~ 1.95	_		0.45		0.45	-
				I _{OL} = 4.0 mA	2.3~2.7			0.4		0.4	
				I _{OL} = 8.0 mA	3.0~3.6			0.4		0.4	
Input leakage current IIN VIN = 0-		V _{IN} = 0~5.	.5V	0~3.6			±0.1	_	±1.0	μA	
Power off leakage of	current	I _{OFF}	V _{IN} = 0~5.5V V _{OUT} = 0~3.6V		0	_	_	1.0	_	10.0	μA
Quiescent supply c	urrent	ICC	$V_{IN} = V_{CC}$	or GND	3.6			1.0		10.0	μA

AC Electrical Characteristics (input $t_r = t_f = 3 \text{ ns}$)

Characteristics	Symbol	Test Condition		Ta = 25°C		Ta = -40~85°C		Unit	
Characteristics	Symbol	Test Condition	V _{CC} (V)	Min	Тур.	Max	Min	Max	Unit
		C _L = 10 pF, R _L = 1 MΩ	0.9	_	41.3	_	_	_	
			1.1~1.3	_	18.0	25.4	1.0	40.8	
			1.4~1.6		9.5	12.2	1.0	13.5	ns
			1.65~ 1.95		7.0	8.7	1.0	9.3	
			2.3~2.7		4.7	5.7	1.0	6.2	
Propagation delay time			3.0~3.6		3.7	4.5	1.0	4.7	
		$C_L = 15 \text{ pF},$ $R_L = 1 \text{ M}\Omega$	0.9		44.4				
	t _{pLH} t _{pHL}		1.1~1.3		19.3	27.7	1.0	46.9	
			1.4~1.6		10.2	13.1	1.0	14.7	
			1.65~ 1.95		7.5	9.3	1.0	9.9	
			2.3~2.7		5.0	5.9	1.0	6.4	
			3.0~3.6		4.0	4.8	1.0	5.2	
		$C_L = 30 \text{ pF},$ $R_L = 1 \text{ M}\Omega$	0.9		55.8		_	_	
			1.1~1.3		24.7	36.3	1.0	59.6	
			1.4~1.6		12.9	16.8	1.0	19.2	
			1.65~ 1.95		9.2	11.5	1.0	12.9	
			2.3~2.7		5.9	7.1	1.0	8.3	
			3.0~3.6		4.9	5.7	1.0	6.6	
Input capacitance	C _{IN}	_	3.6		3	_			pF
Power dissipation capacitance	C _{PD}	(Note 13)	0.9 ~ 3.6		11		_		pF

Note 13: C_{PD} is defined as the value of the internal equivalent capacitance which is calculated from the operating current consumption without load.

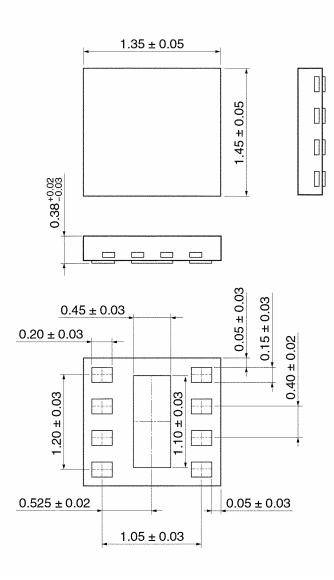
Average operating current can be obtained by the equation:

 $I_{CC (opr.)} = C_{PD} \cdot V_{CC} \cdot f_{IN} + I_{CC}/3$

TOSHIBA

Package Dimensions

CSON8-P-0.4



Weight: 0.002 g (typ.)

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20070701-EN GENERAL

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